

INCHANGE SEMICONDUCTOR

Isc N-Channel MOSFET Transistor

STF10NM65N

FEATURES

- With TO-220F package
- · Low input capacitance and gate charge
- · Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation
- APPLICATIONS
- Switching applications
- · Load switch
- Power management

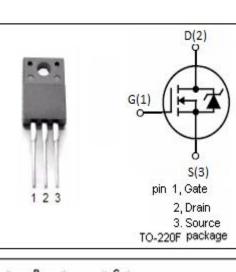
ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

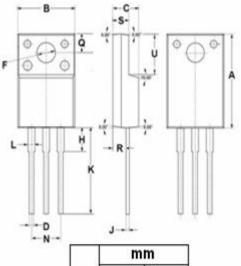
SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	650	V
V_{GSS}	Gate-Source Voltage	±25	V
ID	Drain Current-ContinuousTc=25°C9Tc=100°C5.7		A
I _{DM}	Drain Current-Single Pulsed	36	A
P _D	Total Dissipation @T _C =25°C	25	W
Tj	Max. Operating Junction Temperature	150	°C
T _{stg}	Storage Temperature	-55~150	°C

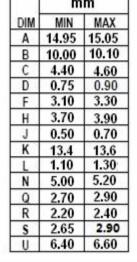
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	5	°C /W
Rth(ch-a)	Channel-to-ambient thermal resistance	62.5	°C /W

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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 1mA	650			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.25mA	2.0		4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =4.5A		0.43	0.48	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =650V; V _{GS} = 0V;Tc=25℃ Tc=125℃			1 100	μA
V _{SDF}	Diode forward voltage	I _{SD} =9A, V _{GS} = 0 V			1.3	v

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